



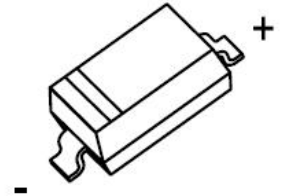
BAV16W FAST SWITCHING DIODE



FEATURES

- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Applications
- High Conductance

MARKING: T6



SOD-123

Maximum Ratings and Electrical Characteristics, Single Diode @T_a=25°C

Parameter	Symbol	Limit	Unit
Non-Repetitive Peak Reverse Voltage	V _{RM}	100	V
Peak Repetitive Peak Reverse Voltage	V _{RRM}		
Working Peak Reverse Voltage	V _{RWM}	100	V
DC Blocking Voltage	V _R		
RMS Reverse Voltage	V _{R(RMS)}	71	V
Forward Continuous Current	I _{FM}	300	mA
Average Rectified Output Current	I _O	150	mA
Non-Repetitive Peak Forward Surge Current @t=8.3ms	I _{FSM}	2.0	A
Power Dissipation	P _d	350	mW
Thermal Resistance from Junction to Ambient(Note 1)	R _{θJA}	357.1	°C/W
Operation Junction and Storage Temperature Range	T _J , T _{STG}	-55~+150	°C

Note 1: Device mounted on 1"x1" FR4 PCB, 1oz single-side copper.



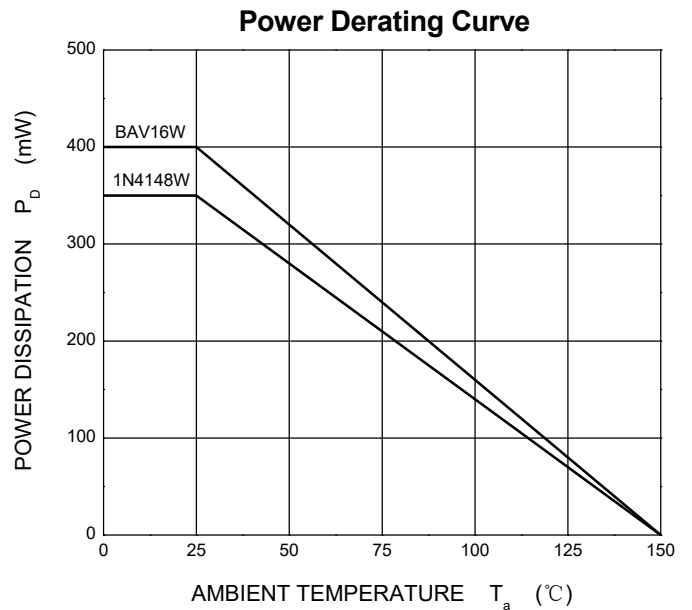
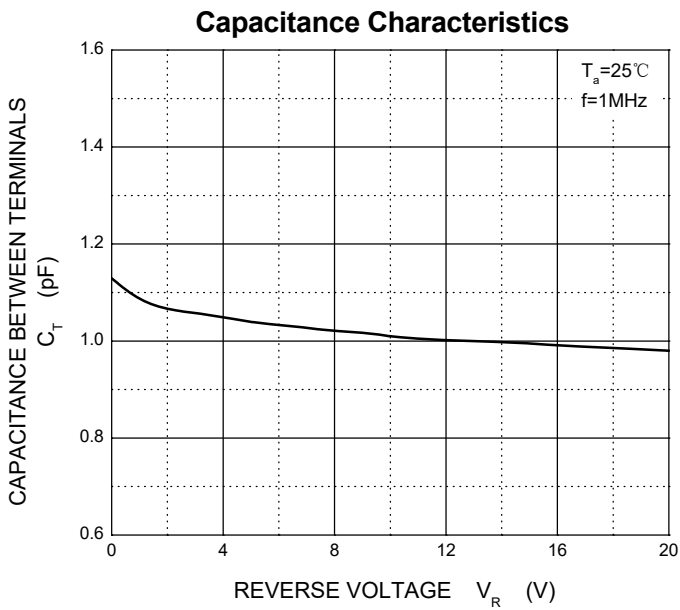
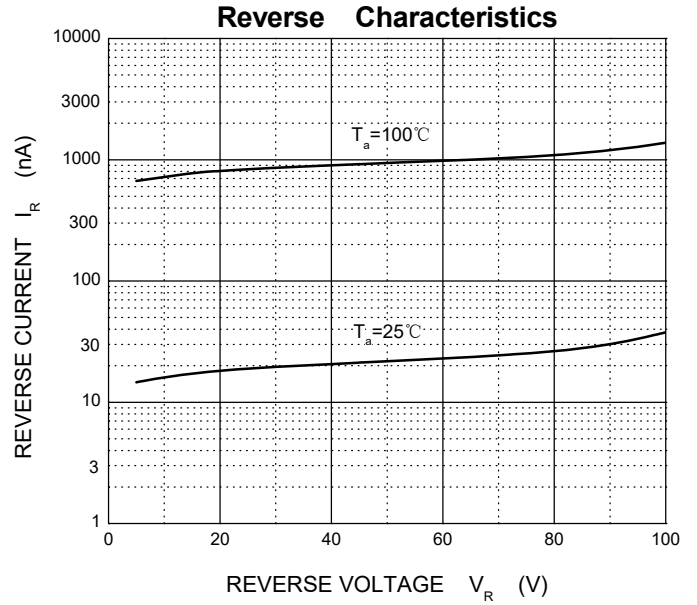
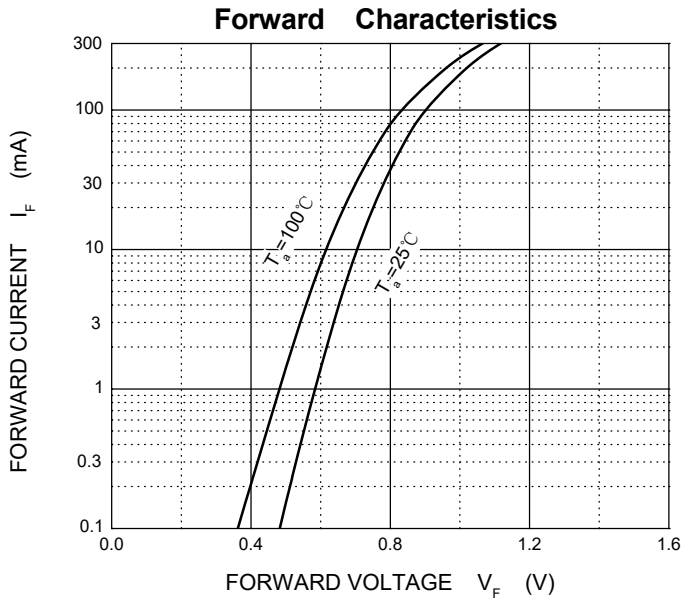
ELECTRICAL CHARACTERISTICS

Electrical Ratings @Ta=25°C

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Forward voltage	V_{F1}			0.715	V	$I_F=1\text{mA}$
	V_{F2}			0.855	V	$I_F=10\text{mA}$
	V_{F3}			1.0	V	$I_F=50\text{mA}$
	V_{F4}			1.25	V	$I_F=150\text{mA}$
Reverse current	I_{R1}			1	μA	$V_R=75\text{V}$
	I_{R2}			25	nA	$V_R=20\text{V}$
Capacitance between terminals	C_T			2	pF	$V_R=0\text{V}, f=1\text{MHz}$
Reverse recovery time	t_{rr}			4	ns	$I_F=I_R=10\text{mA}$ $I_{rr}=0.1I_R, R_L=100\Omega$



Typical Characteristics

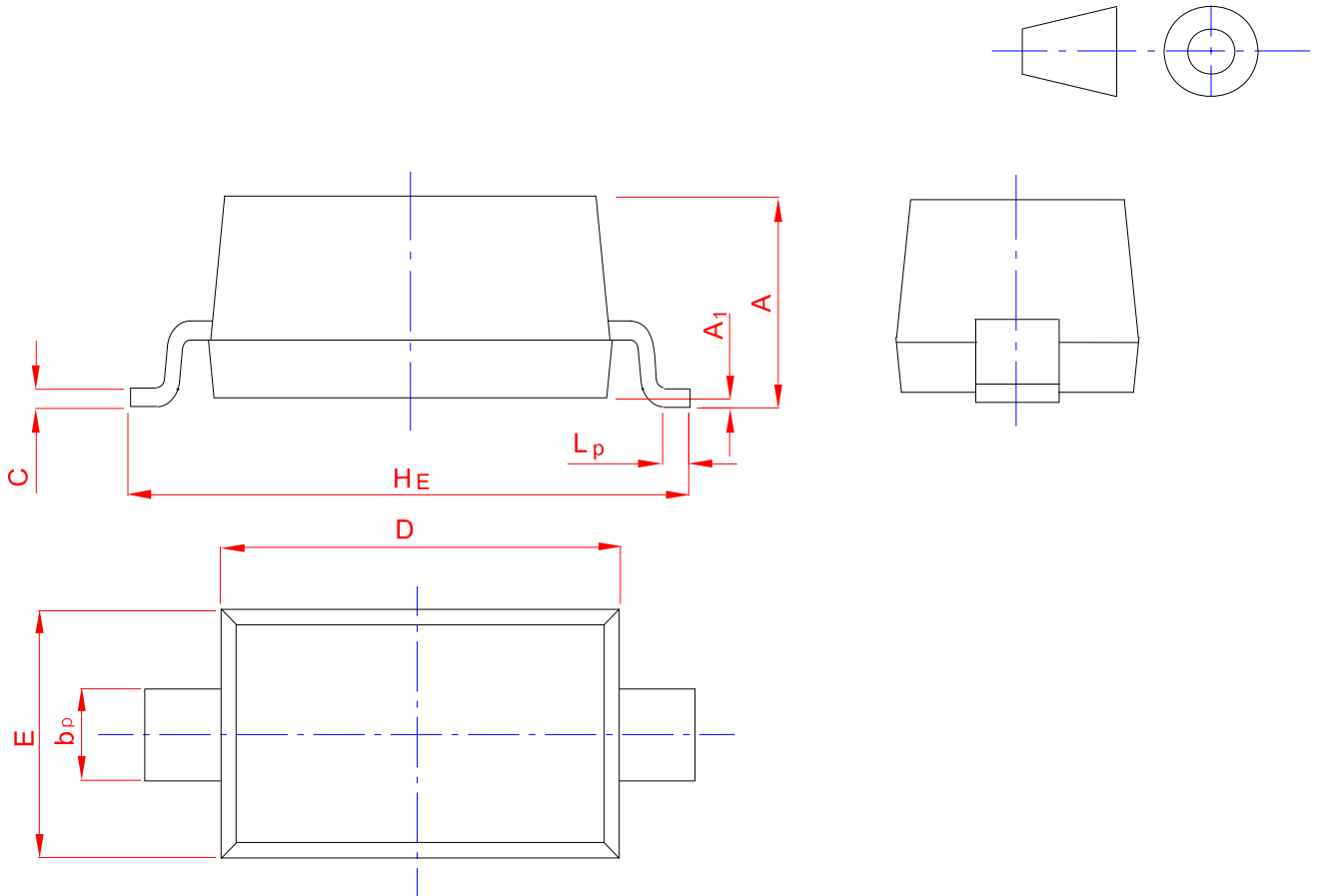




PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-123



UNIT	A	b _p	C	D	E	H _E	A ₁	L _p
mm	1.20	0.60	0.135	2.75	1.65	3.85	0.10	0.50
	0.90	0.50	0.100	2.55	1.55	3.55	0.01	0.20